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# *GdAlSi: A potential candidate for altermagnetic topological Weyl semimetal\**

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Miramare Campus, Leonardo Building, Room 204

and on MS Microsoft (<https://tinyurl.com/yvpdvfe2>)

Spintronics has emerged as a viable alternative to conventional electronics in the past few decades.

On one hand, discovery of topological phases of matter with protected spin-polarized states have shown promising applications while on the other hand, new magnetic materials have shown intriguing phases of collinear antiferromagnets with unconventional spin-splitters. In this work, we report the co-existence of these two interesting phases in a single material: GdAlSi. GdAlSi crystallizes in a body-centered tetragonal structure with a non-centrosymmetric space group  $I41md$  (109), as confirmed by our XRD and optical second harmonic generation experiments. The magnetization data indicates antiferromagnetic (AFM) ordering with an ordering temperature (TN) 32 K. Ab-initio calculations show GdAlSi to be a collinear antiferromagnetic Weyl semimetal (WSM) with an unconventional momentum-dependent spin splitting (also nomenclature as altermagnetism). Fermi arcs, a characteristic feature of WSMs, have been subsequently observed in angle-resolved photoemission spectroscopy (ARPES) measurements performed on GdAlSi single crystals. Electric and magnetic multipole analysis gives a deeper insight into the symmetry mediated momentum-dependent spin splitting which has a strictly non-relativistic origin. To the best of our knowledge, such coexistence of unconventional AFM order and non-trivial topology is unprecedented and has never been observed before in any material which makes GdAlSi a wonder material. Finally, we propose a device which can leverage this unique coexistence leading to practical and efficient topotronic application.



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